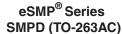
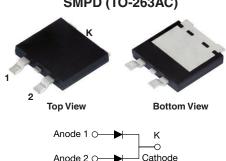


# Ultrafast Rectifier, 2 x 8 A FRED Pt®





#### **LINKS TO ADDITIONAL RESOURCES**



PRIMARY CHARACTERISTICS				
I <sub>F(AV)</sub>	2 x 8 A			
$V_{R}$	600 V			
V <sub>F</sub> at I <sub>F</sub>	0.94 V			
t <sub>rr</sub>	45 ns			
T <sub>J</sub> max.	175 °C			
Package	SMPD (TO-263AC)			
Circuit configuration	Common cathode			

#### **FEATURES**

 $\bullet$  Ultrafast recovery time, reduced  $\mathbf{Q}_{\mathrm{rr}},$  and soft recovery



• 175 °C maximum operating junction temperature

For PFC CRM, snubber operation

COMPLIANT HALOGEN FREE

• Low forward voltage drop

Low lorward voltage dro

Low leakage current

- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Meets JESD 201 class 2 whisker test
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912"><u>www.vishay.com/doc?99912</u></a>

#### **DESCRIPTION / APPLICATIONS**

State of the art ultrafast recovery rectifiers specifically designed with optimized performance of forward voltage drop, ultrafast recovery time, and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness, and reliability characteristics.

These devices are intended for use in PFC, boost, in the AC/DC section of SMPS, freewheeling and clamp diodes.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce power dissipation in the switching element and snubbers.

#### **MECHANICAL DATA**

Case: SMPD (TO-263AC)

Molding compound meets UL 94 V-0 flammability rating

Halogen-free, RoHS-compliant

Terminals: matte tin plated leads, solderable per

J-STD-002

ABSOLUTE MAXIMUM RATINGS					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Peak repetitive reverse voltage		$V_{RRM}$		600	V
Average rectified forward current	per device	- I <sub>F(AV)</sub>	T <sub>solder pad</sub> = 149 °C	16	
	per diode			8	^
Non-repetitive peak surge current	per device	I <sub>FSM</sub> T <sub>J</sub> = 25 °C, 6 ms square pulse	T 05 °C 6 ma aguara mulas	200	A
	per diode		105		

<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Breakdown voltage, blocking voltage	$V_{BR}$ , $V_{R}$	I <sub>R</sub> = 100 μA	600	-	-	
Converse voltage new diede	Forward voltage, per diode V <sub>F</sub>	I <sub>F</sub> = 8 A	-	1.1	1.4	V
Forward voltage, per diode		I <sub>F</sub> = 8 A, T <sub>J</sub> = 150 °C	-	0.94	1.15	
Reverse leakage current, per diode		$V_R = V_R$ rated	-	-	5	
Reverse leakage current, per diode	T <sub>J</sub> = 150 °C, V <sub>R</sub> = V <sub>R</sub> rated	-	20	150	μA	
Junction capacitance, per diode	C <sub>T</sub>	V <sub>R</sub> = 600 V	-	8	-	pF



<b>DYNAMIC RECOVERY CHARACTERISTICS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
		$I_F = 1 A, dI_F/dt = 50 A$	/μs, V <sub>R</sub> = 30 V	-	45	-	
B	+	I <sub>F</sub> = 0.5 A, I <sub>R</sub> = 1 A, I <sub>rr</sub> = 0.25 A		-	-	60	
Reverse recovery time	t <sub>rr</sub>	T <sub>J</sub> = 25 °C	I <sub>F</sub> = 8 A,	-	70	-	ns
		T <sub>J</sub> = 125 °C		=.	100	-	
Dook roopyony gurrent	covery current I <sub>RRM</sub>	T <sub>J</sub> = 25 °C		-	12	-	^
Feak recovery current		IRRM	T <sub>J</sub> = 125 °C	$dI_F/dt = 500 \text{ A/µs},$ $V_B = 400 \text{ V}$	-	17	-
Payaraa raaayan, aharaa	se recovery charge Q <sub>rr</sub> -	T <sub>J</sub> = 25 °C		-	430	-	nC
neverse recovery charge		T <sub>J</sub> = 125 °C		-	850	-	110

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-55	-	+175	°C
Thermal resistance, per diode junction to mount	$R_{thJM}$		-	1.8	2.5	°C/W
Approximate weight				0.55		g
Approximate weight				0.02		OZ.
Marking device		Case style SMPD (TO-263AC)		16CI	DU06	

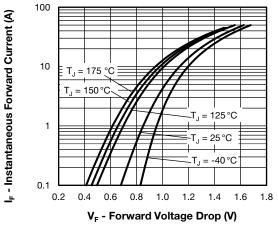


Fig. 1 - Typical Forward Voltage Drop Characteristics

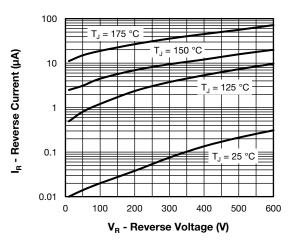


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

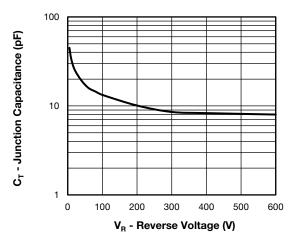


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

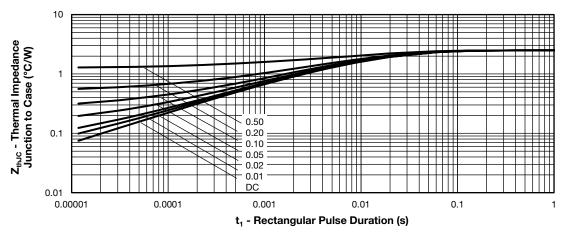


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics

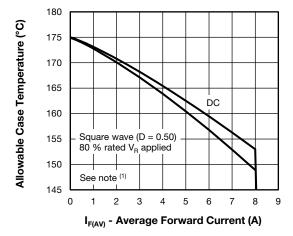


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

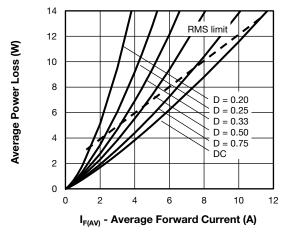


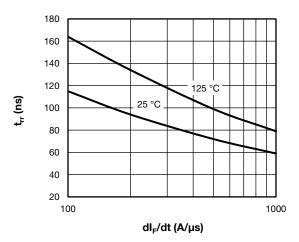
Fig. 6 - Forward Power Loss Characteristics

#### Note

<sup>(1)</sup> Formula used: T<sub>C</sub> = T<sub>J</sub> - (Pd + Pd<sub>REV</sub>) x R<sub>thJC</sub>; Pd = forward power loss = I<sub>F(AV)</sub> x V<sub>FM</sub> at (I<sub>F(AV)</sub>/D) (see fig. 5); Pd<sub>REV</sub> = inverse power loss = V<sub>R1</sub> x I<sub>R</sub> (1 - D); I<sub>R</sub> at V<sub>R1</sub> = rated V<sub>R</sub>

### www.vishay.com

# Vishay Semiconductors





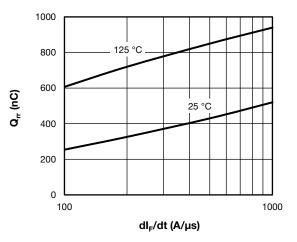
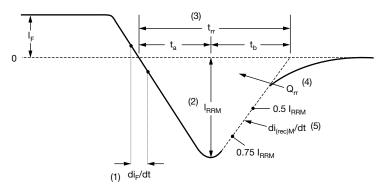


Fig. 8 - Typical Stored Charge vs. dl<sub>E</sub>/dt



- (1) di<sub>F</sub>/dt rate of change of current through zero crossing
- (2)  $I_{RRM}$  peak reverse recovery current
- (3)  $\rm t_{rr}$  reverse recovery time measured from zero crossing point of negative going  $\rm I_F$  to point where a line passing through 0.75  $\rm I_{RRM}$  and 0.50  $\rm I_{RRM}$  extrapolated to zero current.
- (4)  $Q_{rr}$  area under curve defined by  $t_{rr}$  and  $I_{RRM}$

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

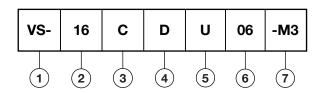
(5) di<sub>(rec)M</sub>/dt - peak rate of change of current during t<sub>b</sub> portion of t<sub>rr</sub>

Fig. 9 - Reverse Recovery Waveform and Definitions



### **ORDERING INFORMATION TABLE**

**Device code** 



1 - Vishay Semiconductors product

Current rating (16 A)

3 - Circuit configuration:

C = common cathode

4 - D = SMPD package

**5** - Process type,

U = ultrafast recovery

6 - Voltage code (06 = 600 V)

7 - -M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

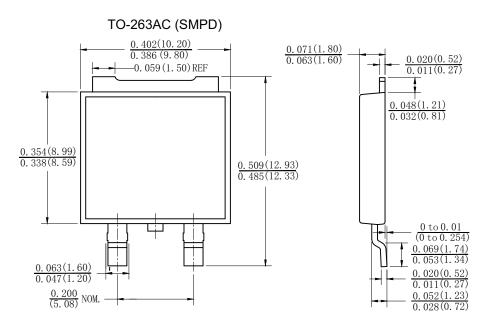
ORDERING INFORMATION (Example)						
PREFERRED P/N	QUANTITY PER REEL	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-16CDU06-M3/I	2000	2000	13" diameter plastic tape and reel			

LINKS TO RELATED DOCUMENTS				
Dimensions <u>www.vishay.com/doc?95604</u>				
Part marking information	www.vishay.com/doc?95566			
Packaging information <u>www.vishay.com/doc?88869</u>				
SPICE model	www.vishay.com/doc?96575			

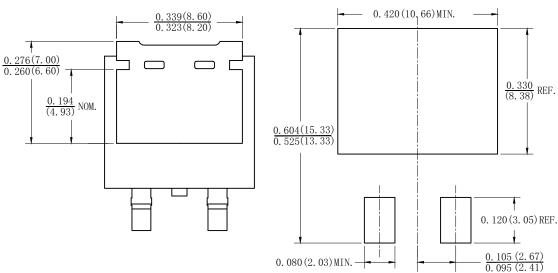


# TO-263AC (SMPD)

### **DIMENSIONS** in inches (millimeters)



### Mounting Pad Layout





## **Legal Disclaimer Notice**

Vishay

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